



NHDTA114/124/144EU series

80 V, 100 mA PNP resistor-equipped transistors

Rev. 1 — 22 July 2020

Product data sheet

1. General description

PNP Resistor-Equipped Transistor (RET) family in a very small SOT323 (SC-70) Surface-Mounted Device (SMD) plastic package.

Table 1. Product overview

Type number	R1	R2	Package		NPN complement:
	k Ω	k Ω	Nexperia	JEITA	
NHDTA114EU	10	10	SOT323	SC-70	NHDTA114EU
NHDTA124EU	22	22			NHDTA124EU
NHDTA144EU	47	47			NHDTA144EU

2. Features and benefits

- 100 mA output current capability
- High breakdown voltage
- Built-in resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- Digital applications
- Cost saving alternative for BC856 series in digital applications
- Controlling IC inputs
- Switching loads

4. Quick reference data

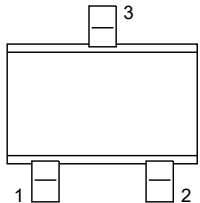
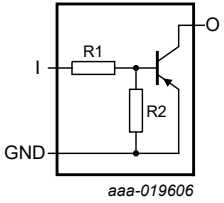
Table 2. Quick reference data

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-80	V
I_O	output current		-	-	-100	mA

5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)		
2	GND	GND (emitter)		
3	O	output (collector)		

6. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
NHDTA114EU	SC-70	plastic surface-mounted package; 3 leads	SOT323
NHDTA124EU			
NHDTA144EU			

7. Marking

Table 5. Marking

Type number	Marking code [1]
NHDTA114EU	5F%
NHDTA124EU	5J%
NHDTA144EU	5L%

[1] % = placeholder for manufacturing site code

8. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Max	Unit	
V_{CBO}	collector-base voltage	open emitter	-	-80	V	
V_{CEO}	collector-emitter voltage	open base	-	-80	V	
V_{EBO}	emitter-base voltage	open collector	-	-10	V	
V_i	input voltage					
	NHDTA114EU		-40	+10	V	
	NHDTA124EU		-60	+10	V	
	NHDTA144EU		-80	+10	V	
I_O	output current		-	-100	mA	
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ °C}$	[1]	-	235	mW
			[2]	-	315	mW
T_j	junction temperature		-	150	°C	
T_{amb}	ambient temperature		-55	150	°C	
T_{stg}	storage temperature		-65	150	°C	

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 Printed-Circuit-Board (PCB); 4-layer copper; tin-plated and standard footprint.

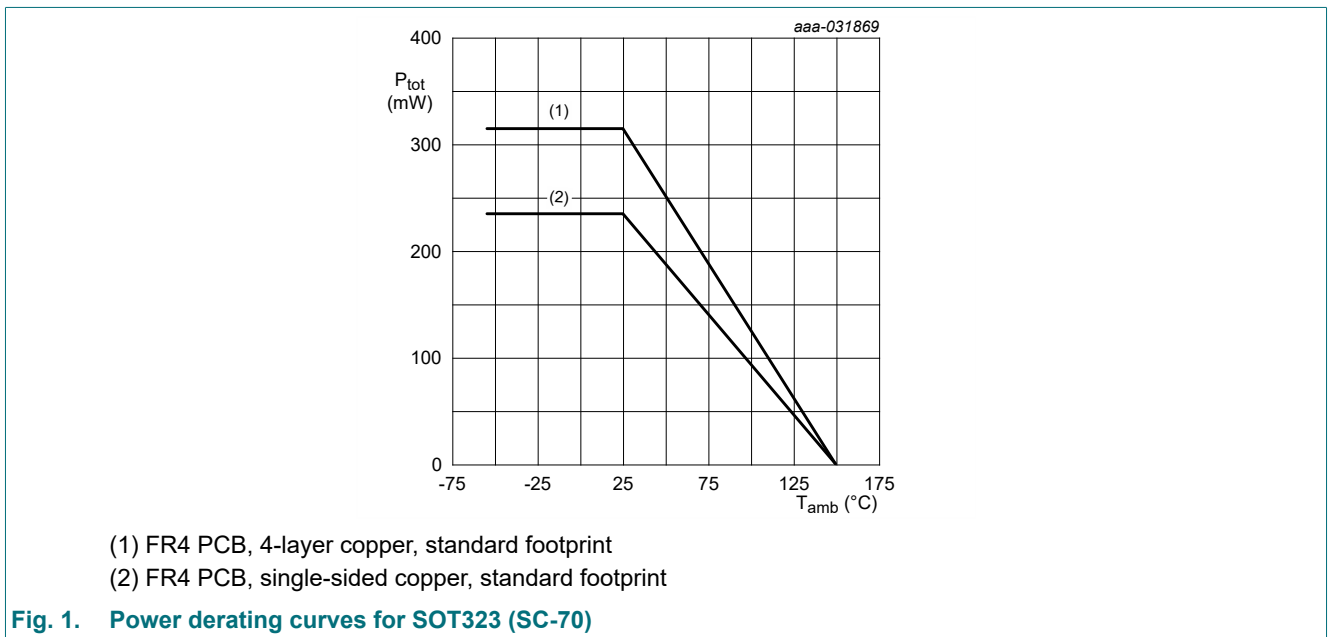


Fig. 1. Power derating curves for SOT323 (SC-70)

9. Thermal characteristics

Table 7. Thermal characteristics

$T_{amb} = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	532	K/W
			[2]	-	-	397	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	150	K/W

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 Printed-Circuit Board (PCB), 4-layer copper, tin-plated and standard footprint.

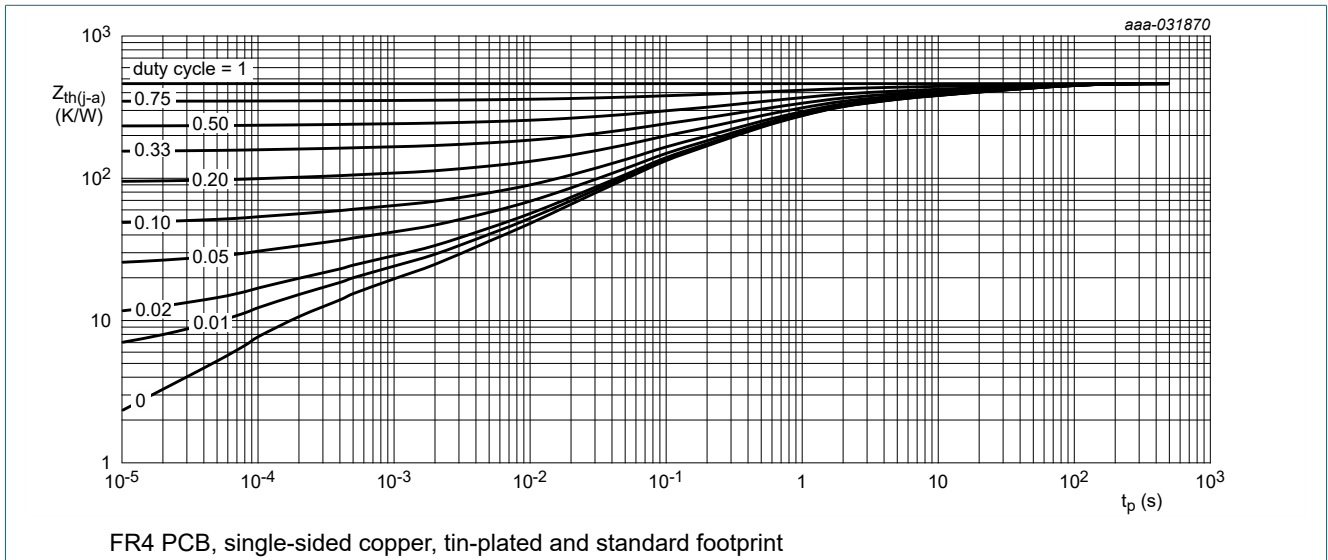


Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

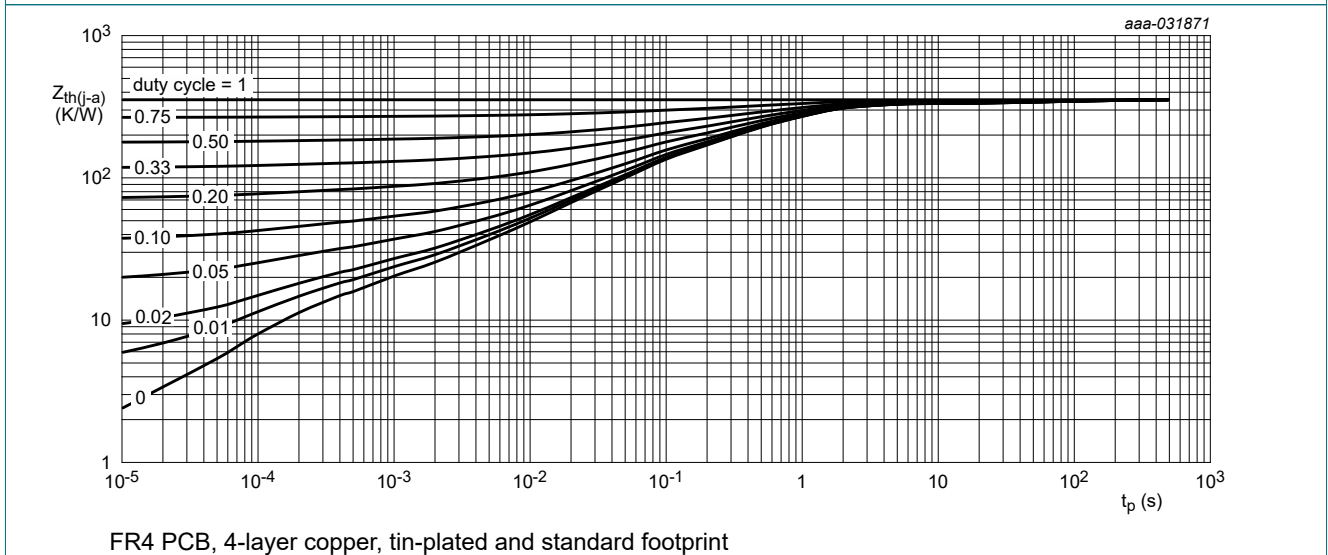


Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

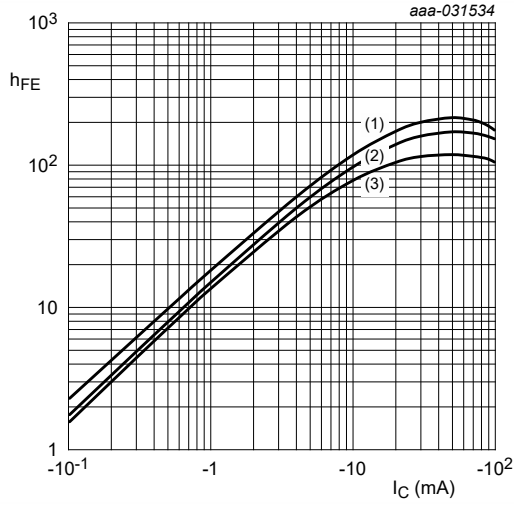
10. Characteristics

Table 8. Characteristics
 $T_{amb} = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = -100\ \mu\text{A}$; $I_E = 0\ \text{A}$	-80	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = -2\ \text{mA}$; $I_B = 0\ \text{A}$	-80	-	-	V
I_{CBO}	collector-base cut-off current	$V_{CB} = -80\ \text{V}$; $I_E = 0\ \text{A}$	-	-	-100	nA
I_{CEO}	collector-emitter cut-off current	$V_{CE} = -60\ \text{V}$; $I_B = 0\ \text{A}$	-	-	-100	nA
		$V_{CE} = -60\ \text{V}$; $I_B = 0\ \text{A}$; $T_j = 150\text{ °C}$	-	-	-5	μA
I_{EBO}	emitter-base cut-off current					
	NHDTA114EU	$V_{EB} = -7\ \text{V}$; $I_C = 0\ \text{A}$	-	-	-600	μA
	NHDTA124EU		-	-	-270	μA
	NHDTA144EU		-	-	-130	μA
h_{FE}	DC current gain					
	NHDTA114EU	$V_{CE} = -5\ \text{V}$; $I_C = -10\ \text{mA}$	50	-	-	
	NHDTA124EU		70	-	-	
	NHDTA144EU		100	-	-	
V_{CEsat}	collector-emitter saturation voltage	$I_C = -10\ \text{mA}$; $I_B = -0.5\ \text{mA}$	-	-	-100	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = -5\ \text{V}$; $I_C = -100\ \mu\text{A}$	-	-1.15	-0.8	V
$V_{I(on)}$	on-state input voltage					
	NHDTA114EU	$V_{CE} = -0.3\ \text{V}$; $I_C = -10\ \text{mA}$	-2.5	-1.8	-	V
	NHDTA124EU		-3	-2.3	-	V
	NHDTA144EU		-5	-3.3	-	V
R1	bias resistor 1 (input)		[1]			
	NHDTA114EU		7	10	13	k Ω
	NHDTA124EU		15.4	22	28.6	k Ω
	NHDTA144EU		33	47	61	k Ω
R2/R1	bias resistor ratio	[1]	0.8	1	1.2	
f_T	transition frequency	$V_{CE} = -5\ \text{V}$; $I_C = -10\ \text{mA}$; $f = 100\ \text{MHz}$	[2]	150	-	MHz
C_c	collector capacitance	$V_{CB} = -10\ \text{V}$; $I_E = I_C = 0\ \text{A}$; $f = 1\ \text{MHz}$	-	-	3	pF

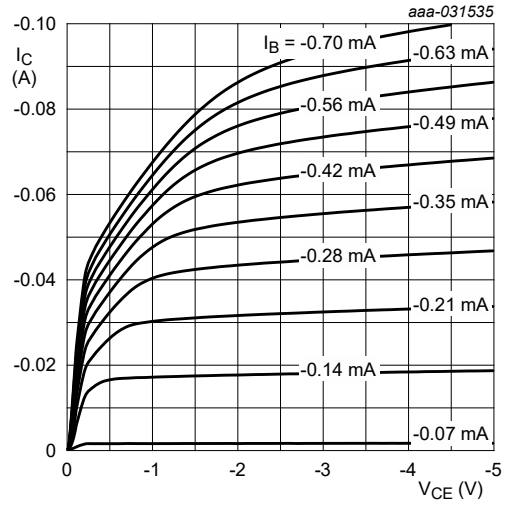
[1] See section "Test information" for resistor calculation and test conditions

[2] Characteristics of built-in transistor



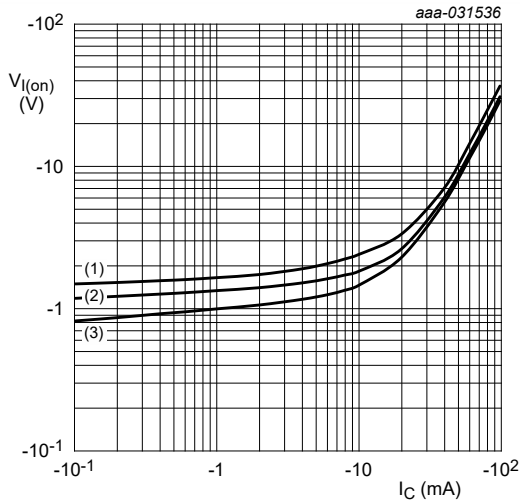
$V_{CE} = -5 \text{ V}$
 (1) $T_{amb} = 100 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = -40 \text{ }^\circ\text{C}$

Fig. 4. NHDTA114EU: DC current gain as a function of collector current; typical values



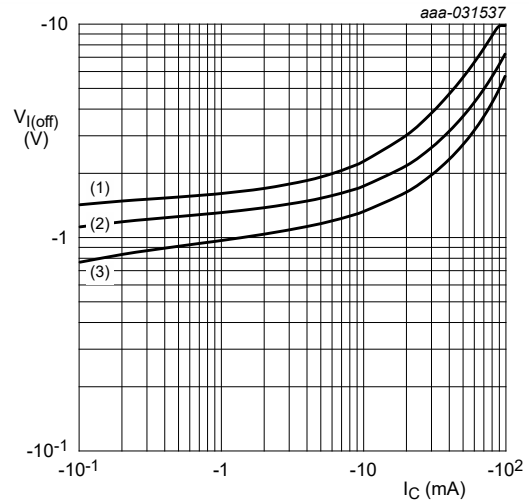
$T_{amb} = 25 \text{ }^\circ\text{C}$

Fig. 5. NHDTA114EU: Collector current as a function of collector-emitter voltage; typical values



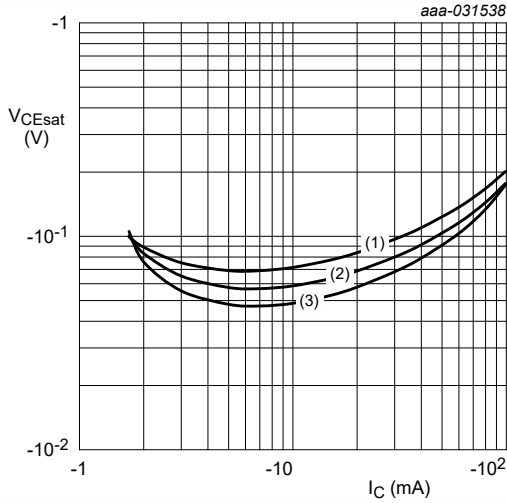
$V_{CE} = -0.3 \text{ V}$
 (1) $T_{amb} = -40 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig. 6. NHDTA114EU: On-state input voltage as a function of collector current; typical values



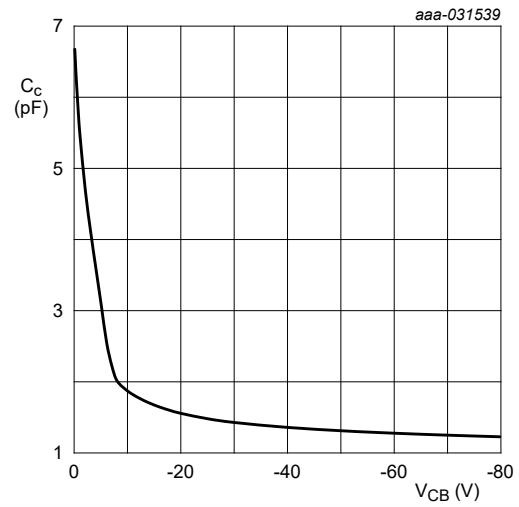
$V_{CE} = -5 \text{ V}$
 (1) $T_{amb} = -40 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig. 7. NHDTA114EU: Off-state input voltage as a function of collector current; typical values



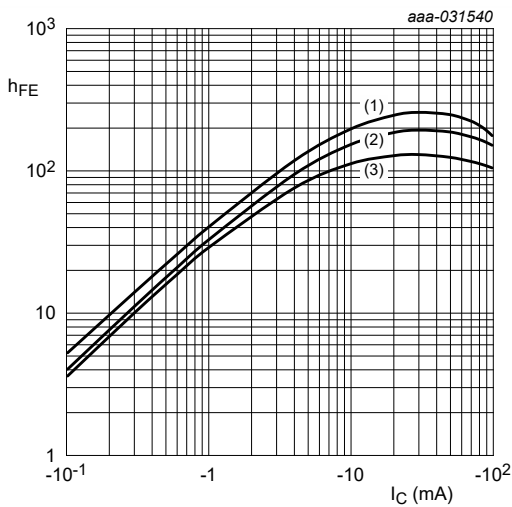
$I_C/I_B = 20$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

Fig. 8. NHDTA114EU: Collector-emitter saturation voltage as a function of collector current; typical values



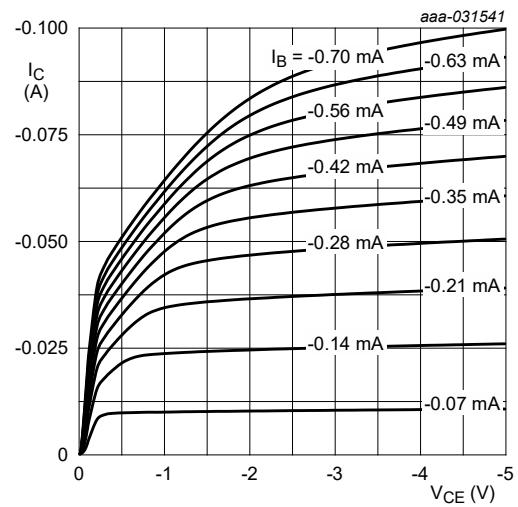
$f = 1\text{ MHz}$
 $T_{amb} = 25\text{ °C}$

Fig. 9. NHDTA114EU: Collector capacitance as a function of collector-base voltage; typical values



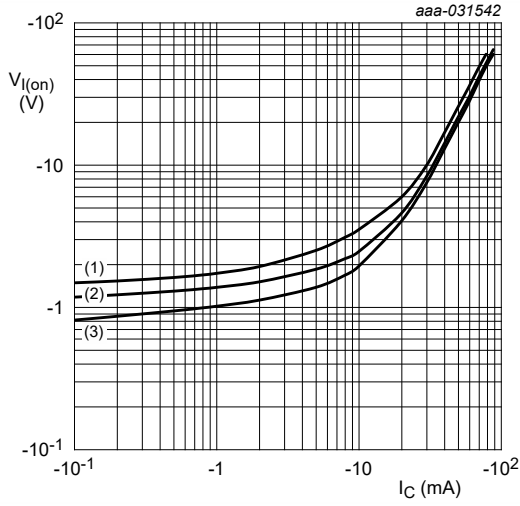
$V_{CE} = -5\text{ V}$
 (1) $T_{amb} = 100\text{ °C}$
 (2) $T_{amb} = 25\text{ °C}$
 (3) $T_{amb} = -40\text{ °C}$

Fig. 10. NHDTA124EU: DC current gain as a function of collector current; typical values



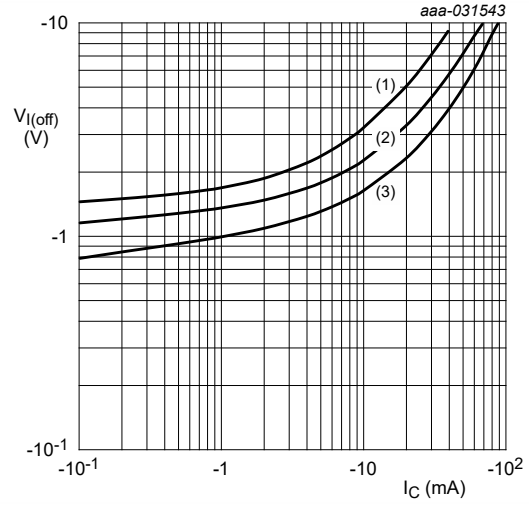
$T_{amb} = 25\text{ °C}$

Fig. 11. NHDTA124EU: Collector current as a function of collector-emitter voltage; typical values



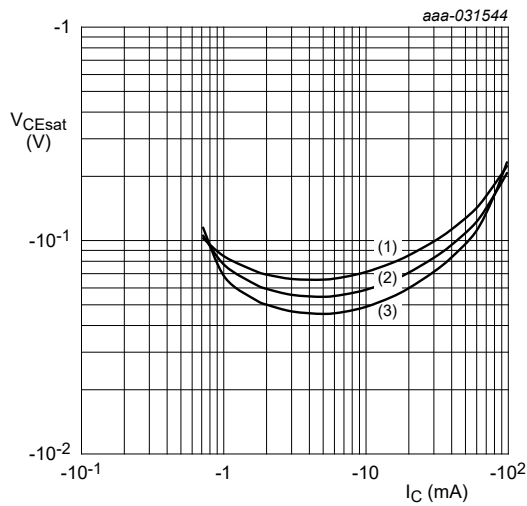
$V_{CE} = -0.3 \text{ V}$
 (1) $T_{amb} = -40 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig. 12. NHDTA124EU: On-state input voltage as a function of collector current; typical values



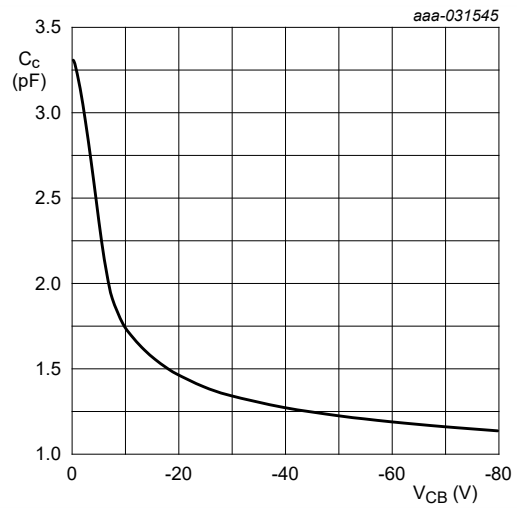
$V_{CE} = -5 \text{ V}$
 (1) $T_{amb} = -40 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig. 13. NHDTA124EU: Off-state input voltage as a function of collector current; typical values



$I_C/I_B = 20$
 (1) $T_{amb} = 100 \text{ }^\circ\text{C}$
 (2) $T_{amb} = 25 \text{ }^\circ\text{C}$
 (3) $T_{amb} = -40 \text{ }^\circ\text{C}$

Fig. 14. NHDTA124EU: Collector-emitter saturation voltage as a function of collector current; typical values



$f = 1 \text{ MHz}$
 $T_{amb} = 25 \text{ }^\circ\text{C}$

Fig. 15. NHDTA124EU: Collector capacitance as a function of collector-base voltage; typical values

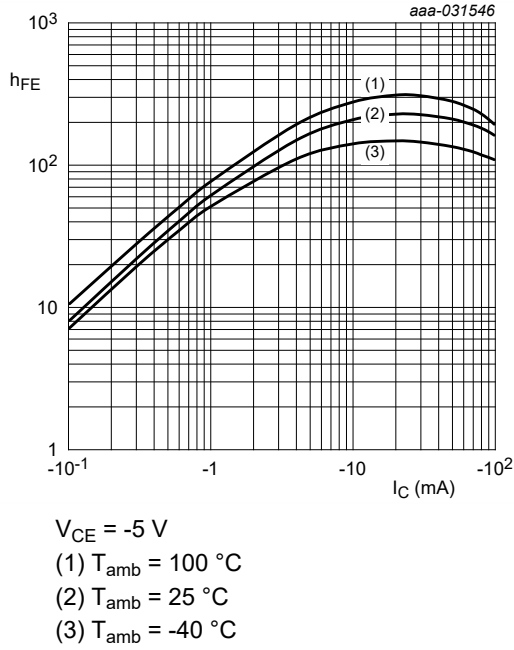


Fig. 16. NHDTA144EU: DC current gain as a function of collector current; typical values

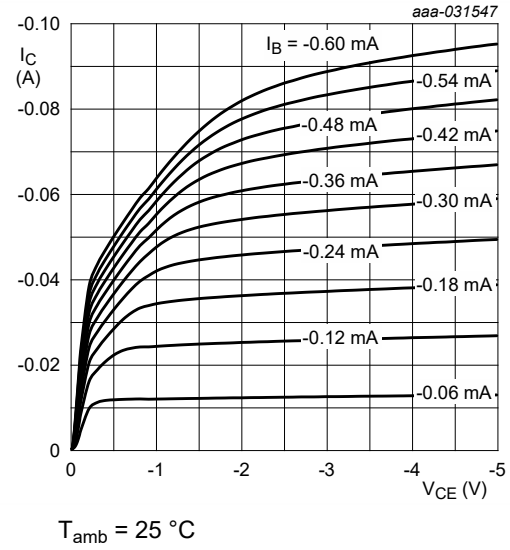


Fig. 17. NHDTA144EU: Collector current as a function of collector-emitter voltage; typical values

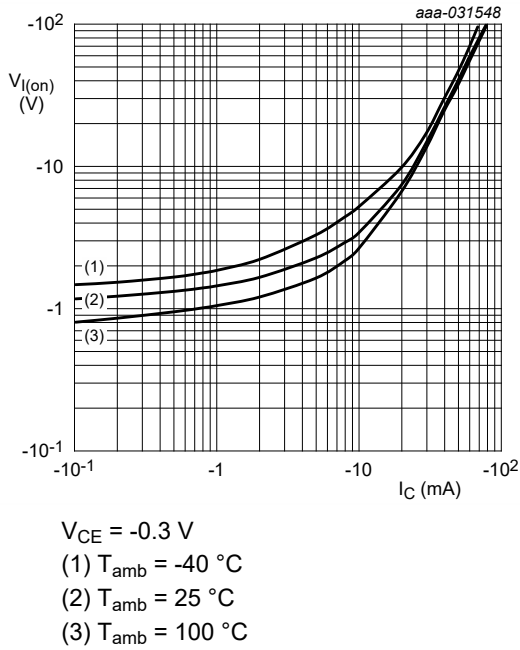


Fig. 18. NHDTA144EU: On-state input voltage as a function of collector current; typical values

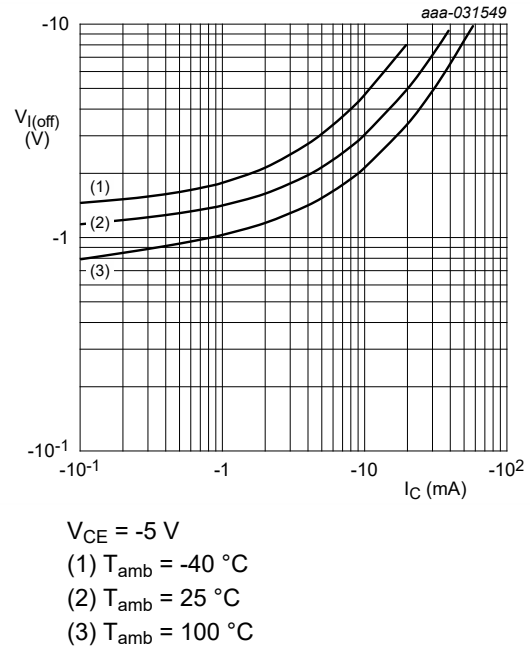
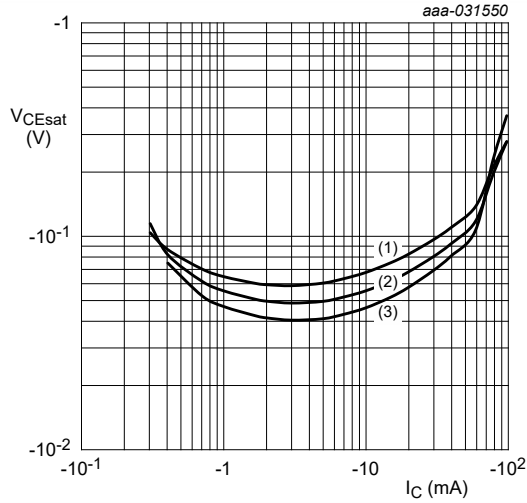
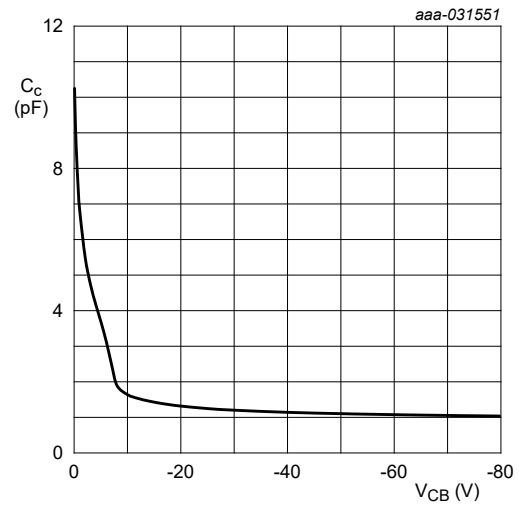


Fig. 19. NHDTA144EU: Off-state input voltage as a function of collector current; typical values



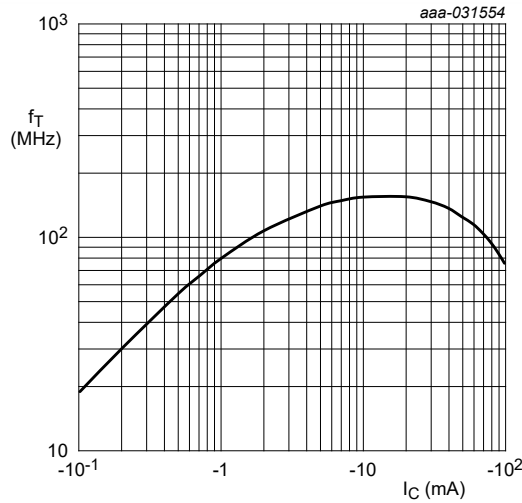
$I_C/I_B = 20$
 (1) $T_{amb} = 100\text{ }^\circ\text{C}$
 (2) $T_{amb} = 25\text{ }^\circ\text{C}$
 (3) $T_{amb} = -40\text{ }^\circ\text{C}$

Fig. 20. NHDTA144EU: Collector-emitter saturation voltage as a function of collector current; typical values



$f = 1\text{ MHz}$
 $T_{amb} = 25\text{ }^\circ\text{C}$

Fig. 21. NHDTA144EU: Collector capacitance as a function of collector-base voltage; typical values of built-in transistor



$f = 100\text{ MHz}$
 $V_{CE} = -5\text{ V}$
 $T_{amb} = 25\text{ }^\circ\text{C}$

Fig. 22. Transition frequency as a function of collector current; typical values of built-in transistor

11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I12) - V(I11)}{I12 - I11}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$

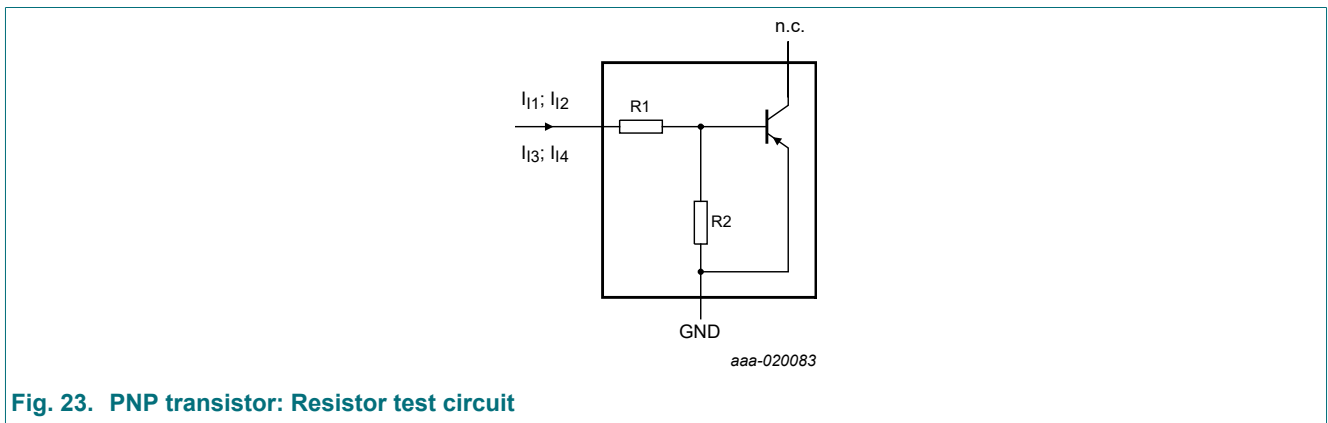


Fig. 23. PNP transistor: Resistor test circuit

Resistor test conditions

Table 9. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I ₁₁	I ₁₂	I ₁₃	I ₁₄
NHDTA114EU	10	10	-800 μA	-1.1 mA	350 μA	450 μA
NHDTA124EU	22	22	-550 μA	-750 μA	150 μA	230 μA
NHDTA144EU	47	47	-250 μA	-350 μA	55 μA	105 μA

12. Package outline

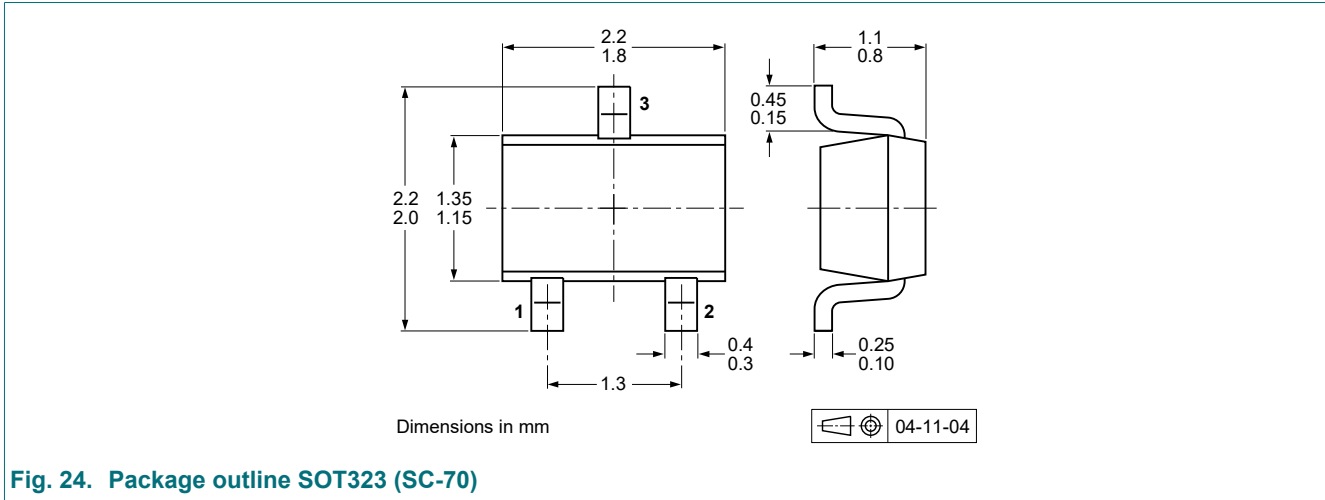


Fig. 24. Package outline SOT323 (SC-70)

13. Soldering

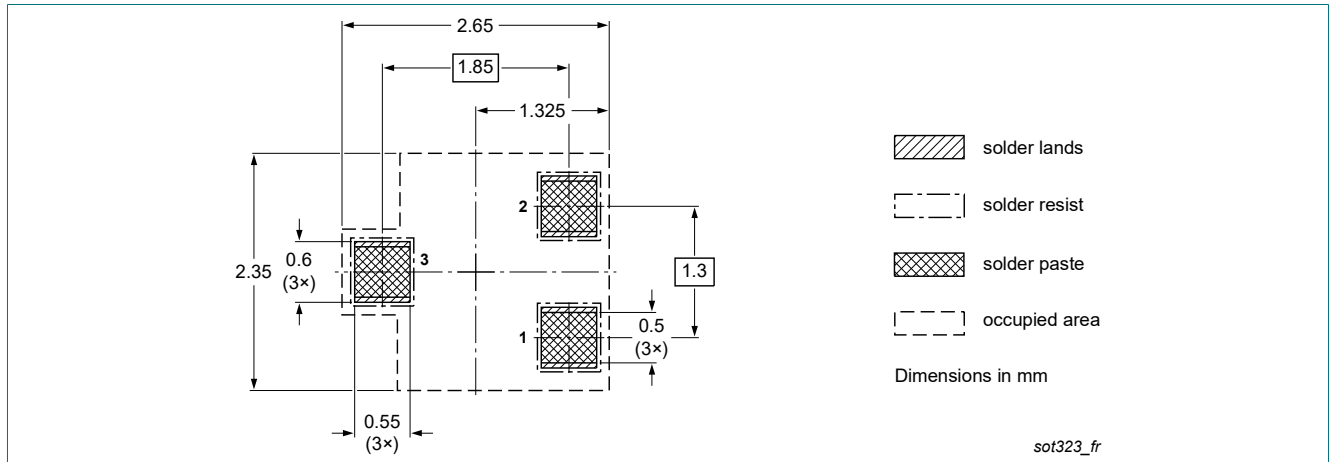


Fig. 25. Reflow soldering footprint SOT323 (SC-70)

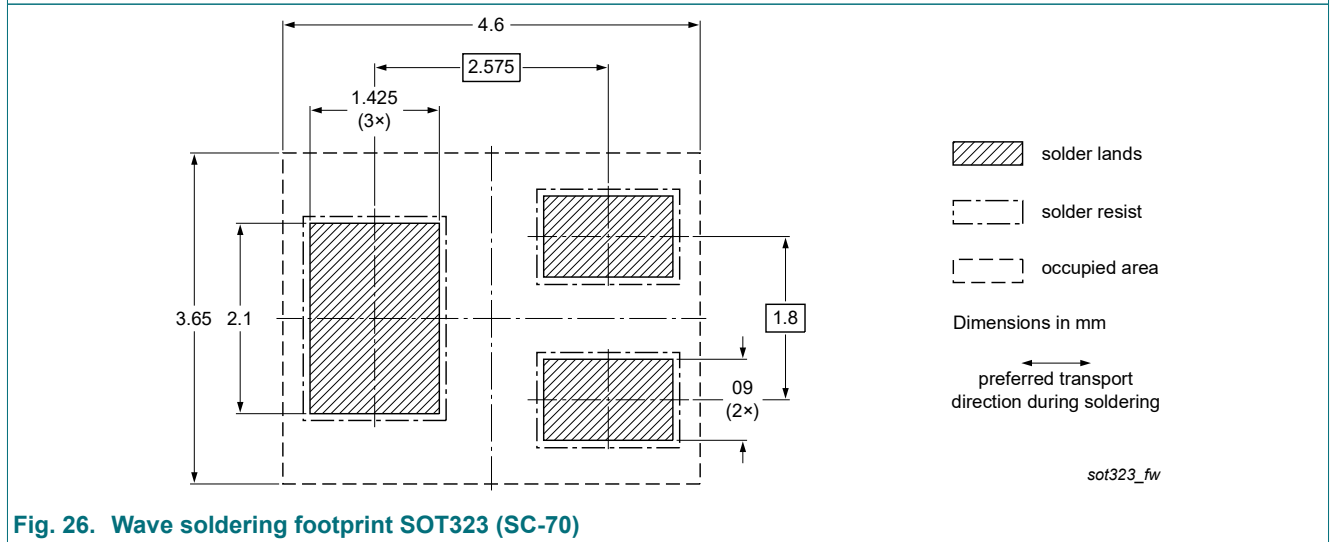


Fig. 26. Wave soldering footprint SOT323 (SC-70)

14. Revision history

Table 10. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
NHDTA114_124_144EU_SER v.1	20200722	Product data sheet	-	-

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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